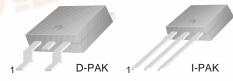


## MJD29/29C

### **General Purpose Amplifier** Low Speed Switching Applications

- Load Formed for Surface Mount Application (No Suffix)
  Straight Lead (I-PAK, "- I" Suffix)
- Electrically Similar to Popular TIP29 and TIP29C



1.Base 2.Collector 3.Emitter

## **NPN Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

| Symbol           | Parameter                                    | Value      | Units |
|------------------|--|------------|-------|
| V <sub>CBO</sub> | Collector-Base Voltage                       |            |       |
| 020              | : MJD29                                      | 40         | V     |
|                  | : MJD29C                                     | 100        | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage                    |            |       |
|                  | : MJD29                                      | 40         | V     |
|                  | : MJD29C                                     | 100        | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage                         | 5          | V     |
| I <sub>C</sub>   | Collector Current (DC)                       | 1          | Α     |
| I <sub>CP</sub>  | Collector Current (Pulse)                    | 3          | Α     |
| I <sub>B</sub>   | Base Current                                 | 0.4        | Α     |
| P <sub>C</sub>   | Collector Dissipation (T <sub>C</sub> =25°C) | 15         | W     |
|                  | Collector Dissipation (T <sub>a</sub> =25°C) | 1.56       | W     |
| TJ               | Junction Temperature                         | 150        | °C    |
| T <sub>STG</sub> | Storage Temperature                          | - 65 ~ 150 | °C    |

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

| Symbol                 | Parameter                             | Test Condition                              | Min.    | Max.   | Units |
|------------------------|---------------------------------------|---|---------|--------|-------|
| V <sub>CEO</sub> (sus) | *Collector-Emitter Sustaining Voltage |   |         |        | 741   |
| 0201                   | : MJD29                               | $I_C = 30 \text{mA}, I_B = 0$               | 40      |        | V     |
|                        | : MJD29C                              |   | 100     | ' 1 Y' | V     |
| I <sub>CEO</sub>       | Collector Cut-off Current             |   | 77.4    | Dr.    |       |
| 020                    | : MJD29                               | $V_{CE} = 40V, I_{B} = 0$                   | AN AN A | 50     | μΑ    |
|                        | : MJD29C                              | $V_{CE} = 60V, I_B = 0$                     |         | 50     | μΑ    |
| I <sub>CES</sub>       | Collector Cut-off Current             | 10/10/                                      |         |        |       |
|                        | : MJD29                               | $V_{CE} = 40V, V_{BE} = 0$                  |         | 20     | μΑ    |
|                        | : MJD29C                              | $V_{CE} = 100V, V_{BE} = 0$                 |         | 20     | μΑ    |
| I <sub>EBO</sub>       | Emitter Cut-off Current               | $V_{BE} = 5V, I_{C} = 0$                    |         | 1      | mA    |
| h <sub>FE</sub>        | *DC Current Gain                      | $V_{CE} = 4V, I_{C} = 0.2A$                 | 40      |        |       |
|                        |                                       | $V_{CE} = 4V$ , $I_C = 1A$                  | 15      | 75     |       |
| V <sub>CE</sub> (sat)  | *Collector-Emitter Saturation Voltage | I <sub>C</sub> = 1A, I <sub>B</sub> = 125mA |         | 0.7    | V     |
| V <sub>BE</sub> (on)   | *Base-Emitter ON Voltage              | $V_{CE} = 4A, I_{C} = 1A$                   |         | 1.3    | V     |
| f <sub>T</sub>         | Current Gain Bandwidth Product        | $V_{CE} = 10V, I_{C} = 200mA$               | 3       |        | MHz   |

\* Pulse Test: PW ≤ 300μs, Duty Cycle ≤ 2%

# **Typical Characteristics**

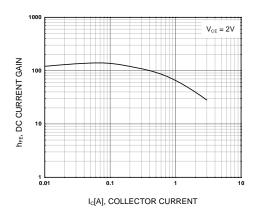


Figure 1. DC current Gain

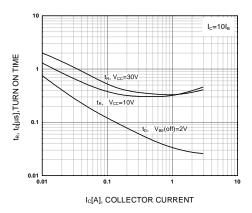


Figure 3. Turn Off Time

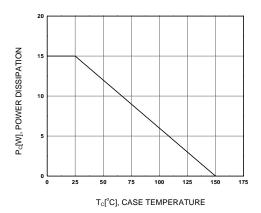


Figure 5. Power Derating

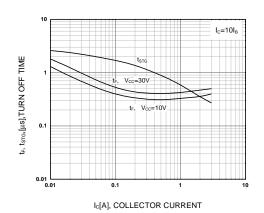


Figure 2. Turn On Time

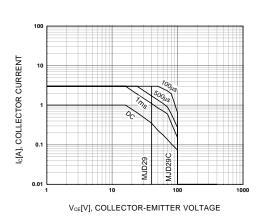
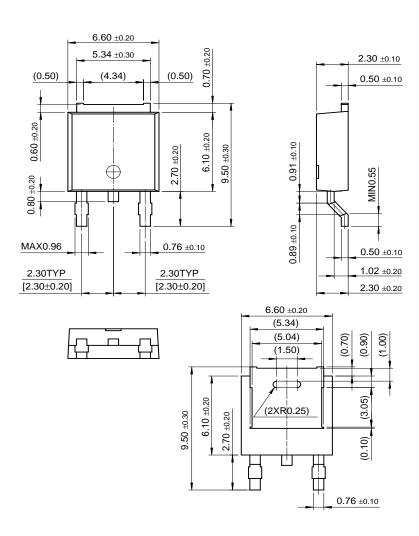


Figure 4. Safe Operating Area

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# **Package Demensions**

# D-PAK



Dimensions in Millimeters

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| E <sup>2</sup> CMOS™ | LittleFET™          | QT Optoelectronics™      | TinyLogic™            |
| EnSigna™             | MicroFET™           | Quiet Series™            | UHC™                  |
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